## **Excellent Integrated System Limited**

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Vishay Semiconductor/Diodes Division</u> <u>VS-MBR160</u>

For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>

### Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VS-MBR160 - DIODE SCHOTTKY 60V 1A DO204AL

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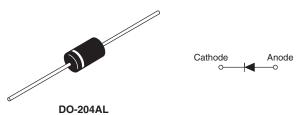


### VS-MBR150, VS-MBR150-M3, VS-MBR160, VS-MBR160-M3

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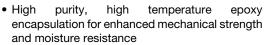
## Schottky Rectifier, 1 A



	Cathode Anode
DO-204AL	

### **FEATURES**

- · Low profile, axial leaded outline
- · Very low forward voltage drop
- · High frequency operation





HALOGEN

FREE

- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and gualified for commercial level
- Halogen-free according to IEC 61249-2-21 definition (-M3 only)

	-	$\sim$	101	FIA	
IJ	E 3	CR	IP1		м

The VS-MBR... axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

PRODUCT SUMMARY				
Package	DO-204AL (DO-41)			
I <sub>F(AV)</sub>	1 A			
$V_R$	50 V, 60 V			
V <sub>F</sub> at I <sub>F</sub>	0.65 V			
I <sub>RM</sub> max.	10.0 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Single die			
E <sub>AS</sub>	2.0 mJ			

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	1.0	А			
V <sub>RRM</sub>		50/60	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	150	Α			
V <sub>F</sub>	1 Apk, T <sub>J</sub> = 125 °C	0.65	V			
T <sub>J</sub>	Range	- 40 to 150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-MBR150	VS-MBR150-M3	VS-MBR160	VS-MBR160-M3	UNITS
Maximum DC reverse voltage	$V_{R}$	50	50	60	60	W
Maximum working peak reverse voltage	$V_{RWM}$	50	50	60	80	v

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average forward current See fig. 4	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 75 °C, r	ectangular waveform	1.0	
Maximum peak one cycle non-repetitive surge current	leo	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	150	Α
See fig. 6	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse			
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 4 mH		2.0	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by, T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical  1.0		Α	

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		1 A		0.75	. v
		2 A	T <sub>J</sub> = 25 °C	0.9	
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	3 A		1.0	
See fig. 1	V FM (')	1 A		0.65	
		2 A	T <sub>J</sub> = 125 °C	0.75	
		3 A		0.82	
		T <sub>J</sub> = 25 °C		0.5	
Maximum reverse leakage current See fig. 2	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 100 °C	V <sub>R</sub> = Rated V <sub>R</sub>	5	mA
566 lig. 2		T <sub>J</sub> = 125 °C		10	
Typical junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		55	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/		V/µs	

#### Note

 $^{(1)}$  Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		- 40 to 150	°C
Maximum thermal resistance, junction to lead	R <sub>thJL</sub> <sup>(2)</sup>	DC operation See fig. 4	80	°C/W
Approximate weight			0.33	g
Approximate weight			0.012	OZ.
Marking dayion		Case style DO 204AL (DO 41)	MBR	R150
Marking device		Case style DO-204AL (DO-41)	MBF	R160

### Notes

<sup>(1)</sup>  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

<sup>(2)</sup> Mounted 1" square PCB, thermal probe connected to lead 2 mm from package



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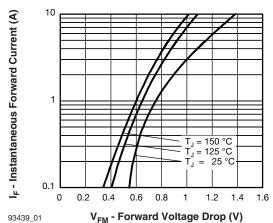
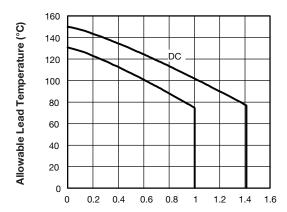


Fig. 1 - Maximum Forward Voltage Drop Characteristics



I<sub>F(AV)</sub> - Average Forward Current (A)
Fig. 4 - Maximum Ambient Temperature vs.
Average Forward Current, Printed Circuit Board Mounted

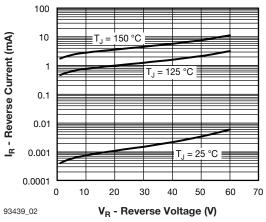


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

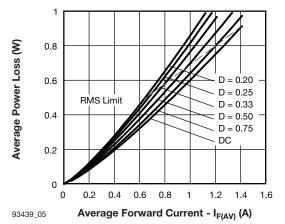


Fig. 5 - Forward Power Loss Characteristics

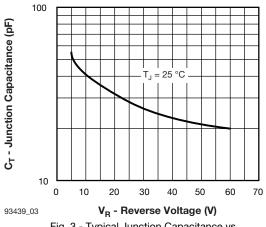


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

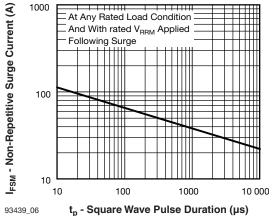


Fig. 6 - Maximum Non-Repetitive Surge Current

#### Note

(1) Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>

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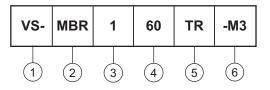
## VS-MBR150, VS-MBR150-M3, VS-MBR160, VS-MBR160-M3

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### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- 2 Schottky MBR series
- Gurrent rating: 1 = 1 A
- Voltage rating 50 = 50 V 60 = 60 V
- TR = Tape and reel package
  None = Bulk package
- 6 Environmental digit
  - None = Lead (Pb)-free and RoHS compliant
  - -M3 = Halogen-free, RoHS compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-MBR150	1000	1000	Bulk	
VS-MBR150TR	5000	5000	Tape and reel	
VS-MBR150-M3	1000	1000	Bulk	
VS-MBR150TR-M3	5000	5000	Tape and reel	
VS-MBR160	1000	1000	Bulk	
VS-MBR160TR	5000	5000	Tape and reel	
VS-MBR160-M3	1000	1000	Bulk	
VS-MBR160TR-M3	5000	5000	Tape and reel	

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95241</u>				
Part marking information	www.vishay.com/doc?95304			
Packaging information	www.vishay.com/doc?95338			

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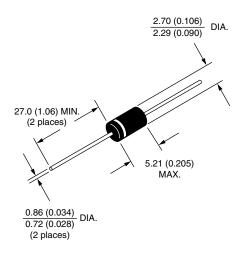


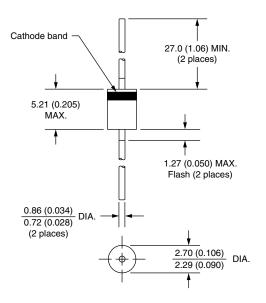
### **Outline Dimensions**

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## Axial DO-204AL (DO-41)

### **DIMENSIONS** in millimeters (inches)







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